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**SEMITOR<sup>®</sup> 2**

## IGBT Module

**SK8GD126**

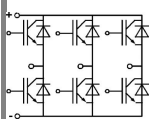
Preliminary Data

### Features

- Fast TRENCH IGBTs
- Soft freewheeling diodes in CAL High Density technology
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)

### Typical Applications

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS



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Absolute Maximum Ratings		T <sub>s</sub> = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
V <sub>CES</sub>	T <sub>j</sub> = 25 °C	1200	V
I <sub>C</sub>	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 25 °C	15 A
		T <sub>s</sub> = 80 °C	10 A
I <sub>CRM</sub>	I <sub>CRM</sub> = 2 × I <sub>Cnom</sub>	16	A
V <sub>GES</sub>		± 20	V
t <sub>psc</sub>	V <sub>CC</sub> = 600 V; V <sub>GE</sub> ≤ 20 V; T <sub>j</sub> = 125 °C V <sub>CES</sub> < 1200 V	10	µs
<b>Inverse Diode</b>			
I <sub>F</sub>	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 25 °C	13 A
		T <sub>s</sub> = 80 °C	9 A
I <sub>FRM</sub>	I <sub>FRM</sub> = 2 × I <sub>Fnom</sub>		A
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms; half sine wave T <sub>j</sub> = 150 °C	55	A
<b>Module</b>			
I <sub>t(RMS)</sub>			A
T <sub>vj</sub>		-40 ... +150	°C
T <sub>stg</sub>		-40 ... +125	°C
V <sub>isol</sub>	AC, 1 min.	2500	V

Characteristics		T <sub>s</sub> = 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
V <sub>GE(th)</sub>	V <sub>GE</sub> = V <sub>CE</sub> , I <sub>C</sub> = 0,3 mA	5	5,8	6,5	V
I <sub>CES</sub>	V <sub>GE</sub> = 1200 V, V <sub>CE</sub> = V <sub>CES</sub>	T <sub>j</sub> = 25 °C		0,05	mA
		T <sub>j</sub> = 125 °C			mA
I <sub>GES</sub>	V <sub>CE</sub> = 0 V, V <sub>GE</sub> = 20 V	T <sub>j</sub> = 25 °C		120	nA
		T <sub>j</sub> = 125 °C			nA
V <sub>CE0</sub>		T <sub>j</sub> = 25 °C	1	1,2	V
		T <sub>j</sub> = 125 °C	0,9		V
r <sub>CE</sub>	V <sub>GE</sub> = 15 V	T <sub>j</sub> = 25 °C	87,5		mΩ
		T <sub>j</sub> = 125 °C	137		mΩ
V <sub>CE(sat)</sub>	I <sub>Cnom</sub> = 8 A, V <sub>GE</sub> = 15 V	T <sub>j</sub> = 25 °C <sub>chiplev.</sub>	1,7	2,2	V
		T <sub>j</sub> = 125 °C <sub>chiplev.</sub>	2		V
C <sub>ies</sub>	V <sub>CE</sub> = 25, V <sub>GE</sub> = 0 V	f = 1 MHz	0,605		nF
C <sub>oes</sub>			0,037		nF
C <sub>res</sub>			0,029		nF
t <sub>d(on)</sub>	R <sub>Gon</sub> = 50 Ω	V <sub>CC</sub> = 600V	85		ns
t <sub>r</sub>			30		ns
E <sub>on</sub>	R <sub>Goff</sub> = 50 Ω	I <sub>Cnom</sub> = 8A	0,78		mJ
t <sub>d(off)</sub>		T <sub>j</sub> = 125 °C	430		ns
t <sub>f</sub>		V <sub>GE</sub> = ±15V	90		ns
E <sub>off</sub>			0,96		mJ
R <sub>th(j-s)</sub>	per IGBT			2	K/W

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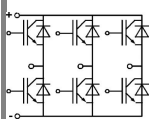
#### Preliminary Data

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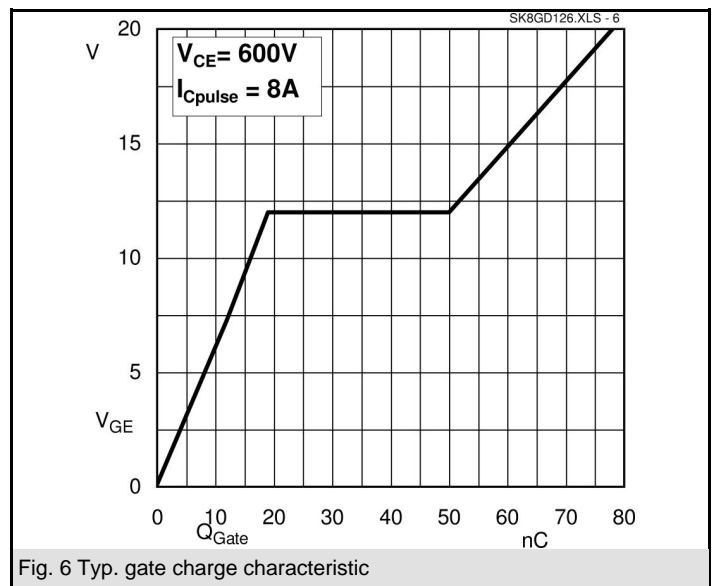
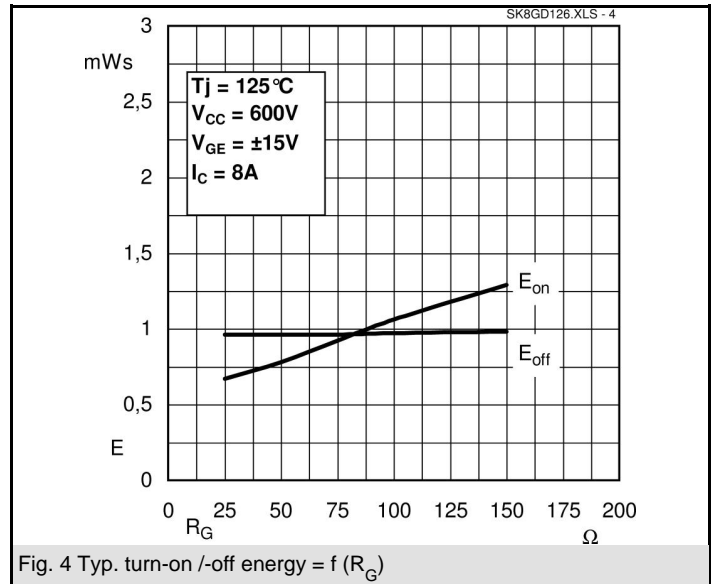
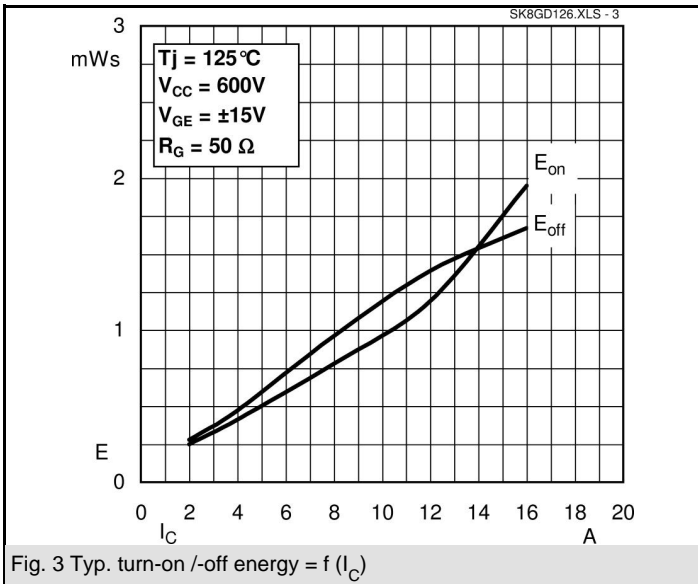
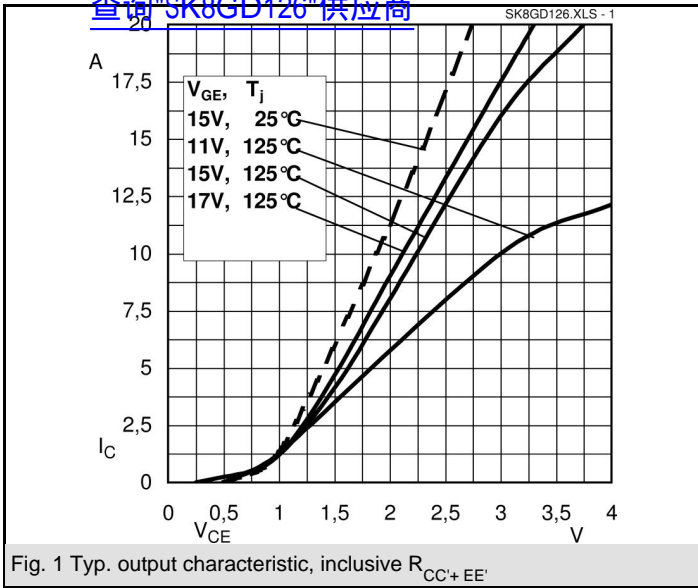
#### Characteristics

Symbol	Conditions	min.	typ.	max.	Units
<b>Inverse Diode</b>					
$V_F = V_{EC}$	$I_{Fnom} = 8 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$	1,9	22	V
		$T_j = 125 \text{ }^\circ\text{C}_{\text{chiplev.}}$	2	2,4	V
$V_{F0}$		$T_j = 25 \text{ }^\circ\text{C}$	1	1,1	V
		$T_j = 125 \text{ }^\circ\text{C}$	0,8		V
$r_F$		$T_j = 25 \text{ }^\circ\text{C}$	112	138	mΩ
		$T_j = 125 \text{ }^\circ\text{C}$	150		mΩ
$I_{RRM}$	$I_{Fnom} = 8 \text{ A}$	$T_j = 125 \text{ }^\circ\text{C}$	9,4		A
$Q_{rr}$	$di/dt = -300 \text{ A}/\mu\text{s}$		1,5		μC
$E_{rr}$	$V_{CC} = 600\text{V}$		20,6		mJ
$R_{th(j-s)D}$	per diode			2,8	K/W
$M_s$	to heat sink			2	Nm
w			21		g

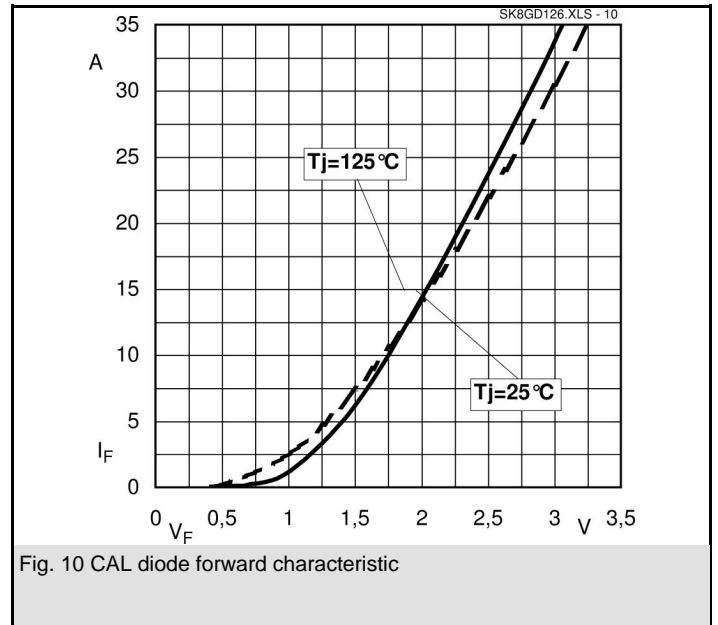
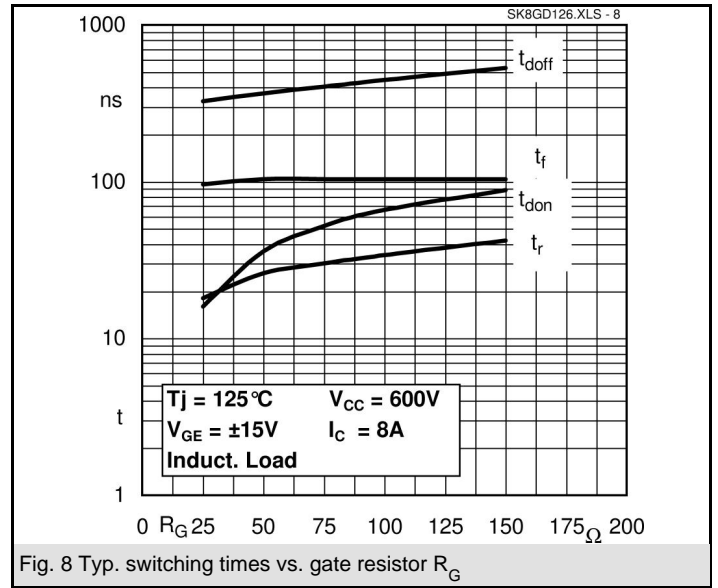
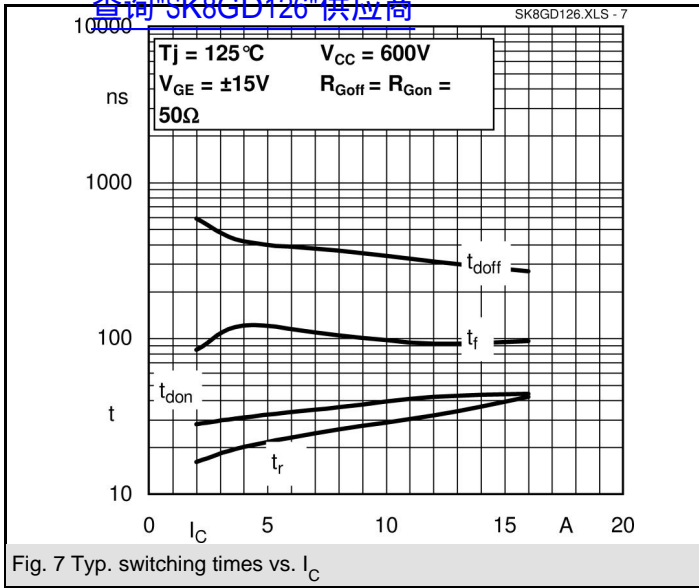
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

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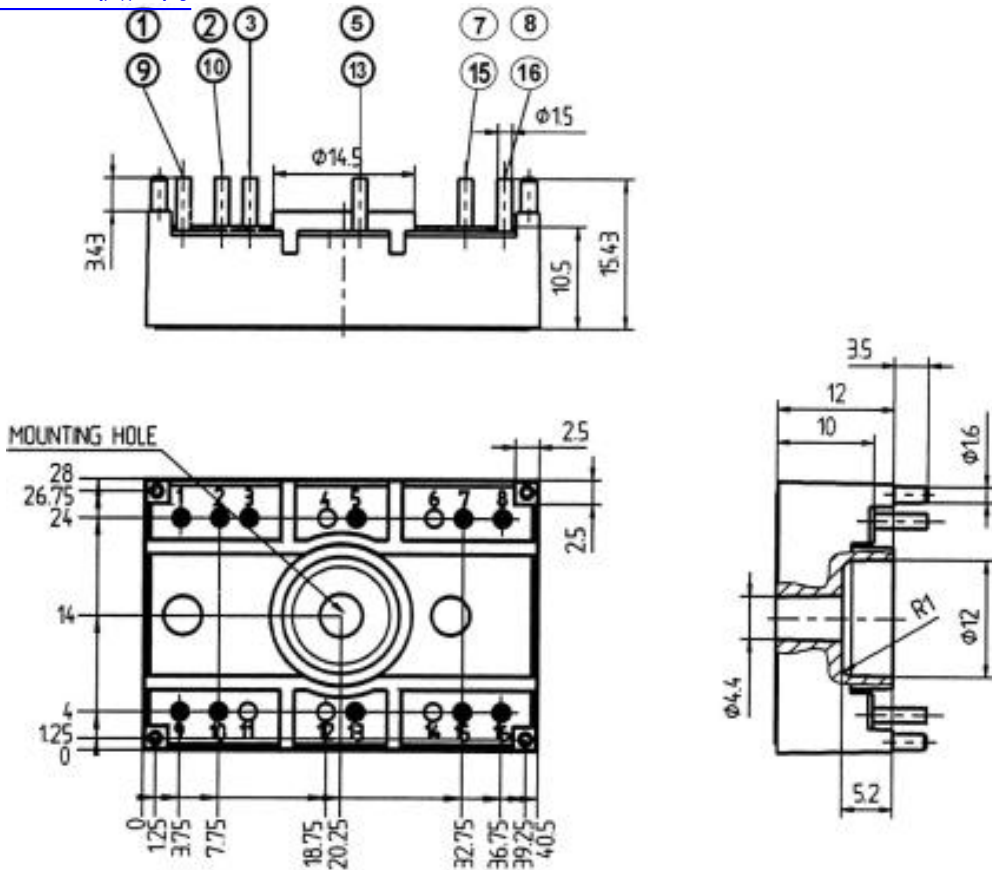
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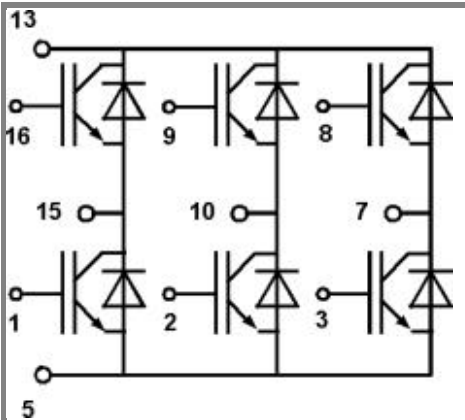
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no. E 63 532



Case T47 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T47

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